

# ESC201: INTRODUCTION TO ELECTRONICS

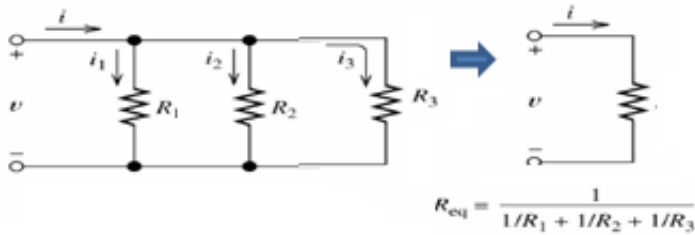
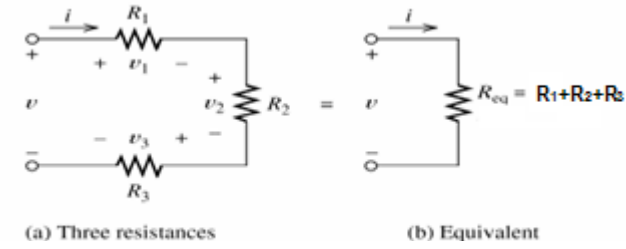
## MODULE 2: ELEMENTS WITH MEMORY



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IIT Kanpur

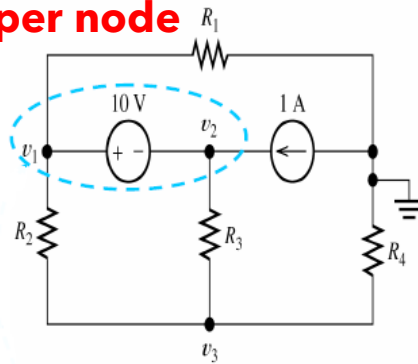
# Summary

## Series/Parallel resistances



## Nodal Analysis:

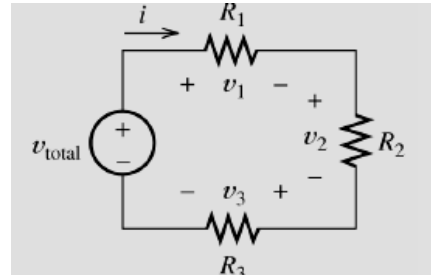
1. Identify and number the nodes
2. Choose a reference node
3. Write KCL for each node such that Sum of currents leaving a node is zero



## Mesh Analysis

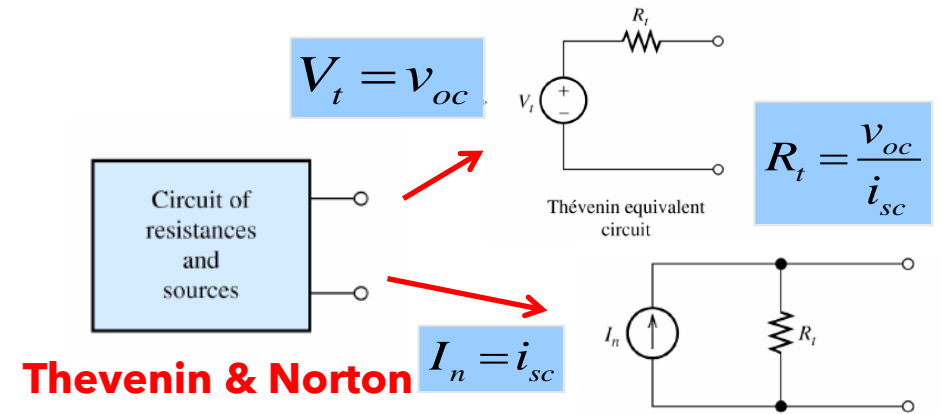
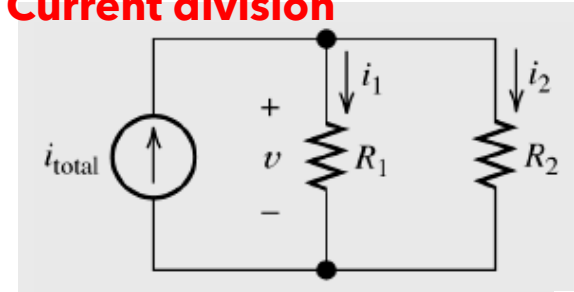
1. Assign mesh currents  $i_1, i_2, \dots, i_n$  to the  $n$  meshes.
2. Apply KVL to each of the  $n$  meshes. Use Ohm's law to express the voltages in terms of the mesh currents.
3. Solve the resulting  $n$  simultaneous equations to get the mesh currents.

## Voltage division



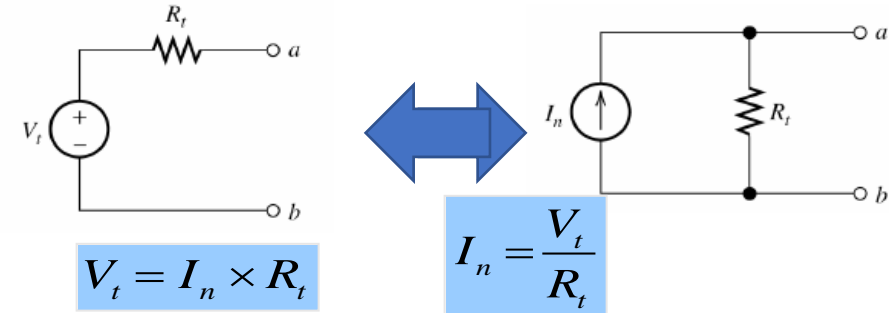
$$v_2 = R_2 i = \frac{R_2}{R_1 + R_2 + R_3} v_{total}$$

## Current division



## Thevenin & Norton

## Source Transformation



The **superposition principle** states that the total response is the sum of the responses to each of the independent sources acting individually.

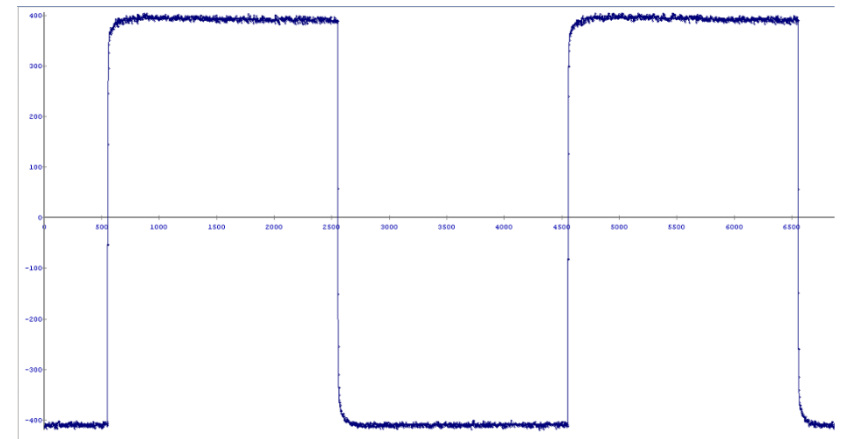
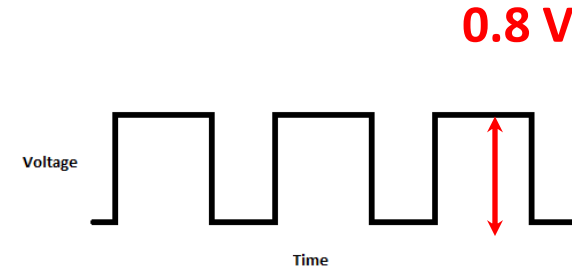
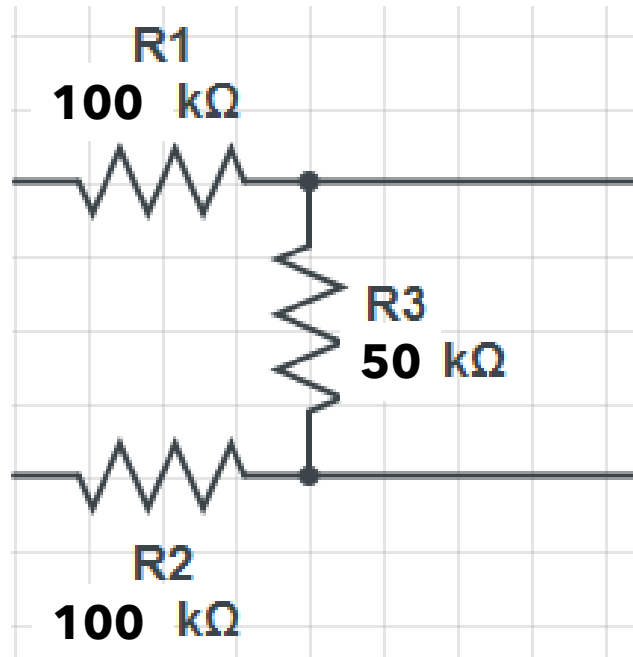
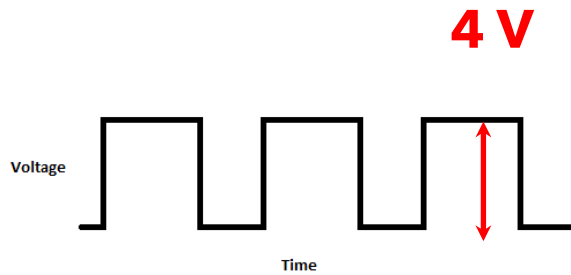
# Storage devices

- Story so far:
  - Resistors, Independent and dependent voltage and current sources
  - Output depends on current input

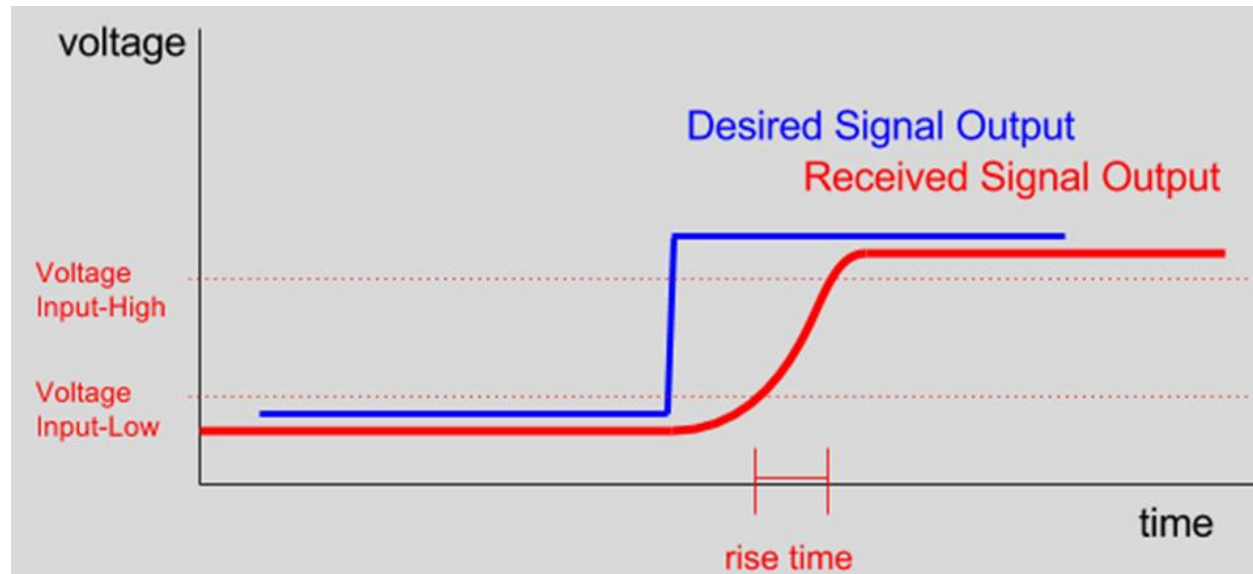
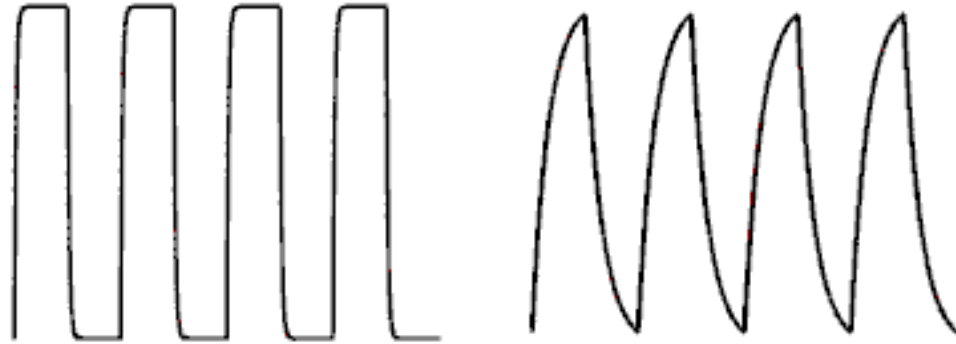
$$V_o(t) = f(V_I(t))$$

- Memory-less!
- Capacitors & Inductors
  - $V_o(t)$  depends on  $V_I(\tau)$  for all  $\tau \leq t$
- Elements with memory
  - Depends on the rate of change of input signals

# Example: potential divider



# Non-zero rise time

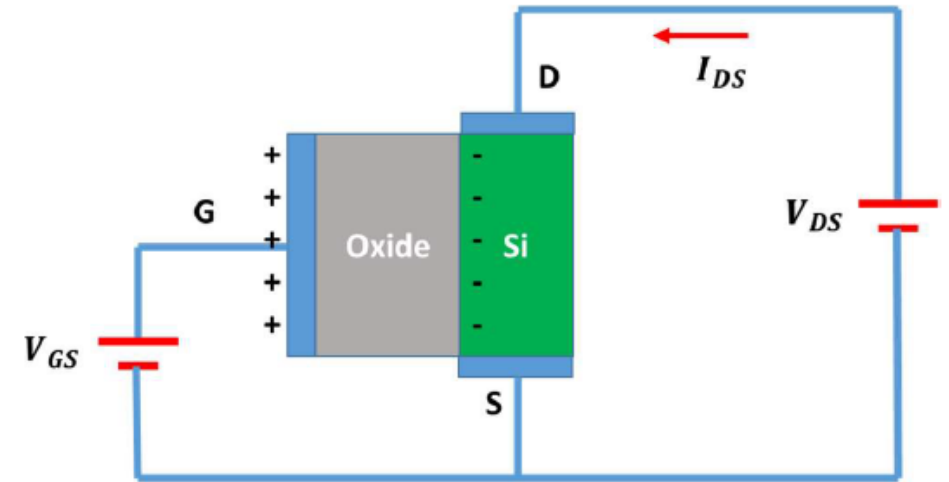
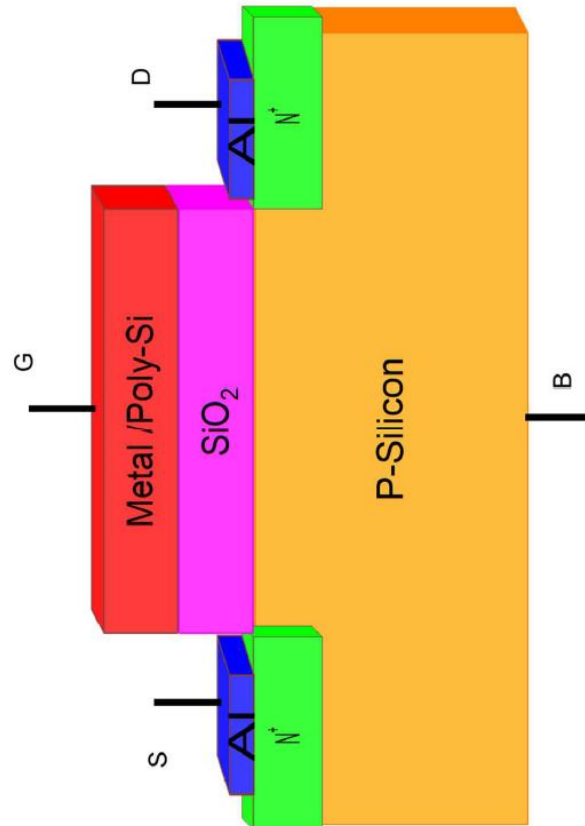
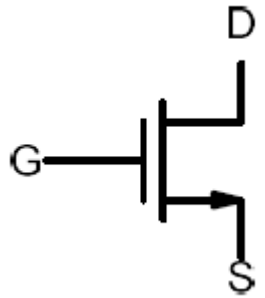


Intel i7 Mobile Processors	Freq. (GHz)	Year
Clarksfield (45 nm)	2.13	2009
Arrandale (32 nm)	2.67	2010
Sandy bridge (32 nm)	2.7	2011
Ivy bridge (22 nm)	2.9	2012
Haswell (22nm)	2.9	2013
Broadwell (14 nm)	3.1	2014
Skylake (14 nm)	3.3	2015
Kaby-Lake (14 nm)	3.5	2017

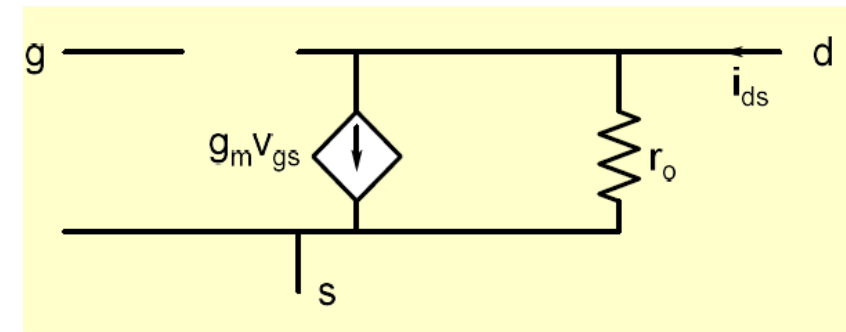
Elements may oppose any change in voltage or current!

# MOSFETs: Workhorse of Semiconductor Industry

MOSFET : Metal Oxide Semiconductor Field effect Transistor



Drain current is controlled by gate voltage



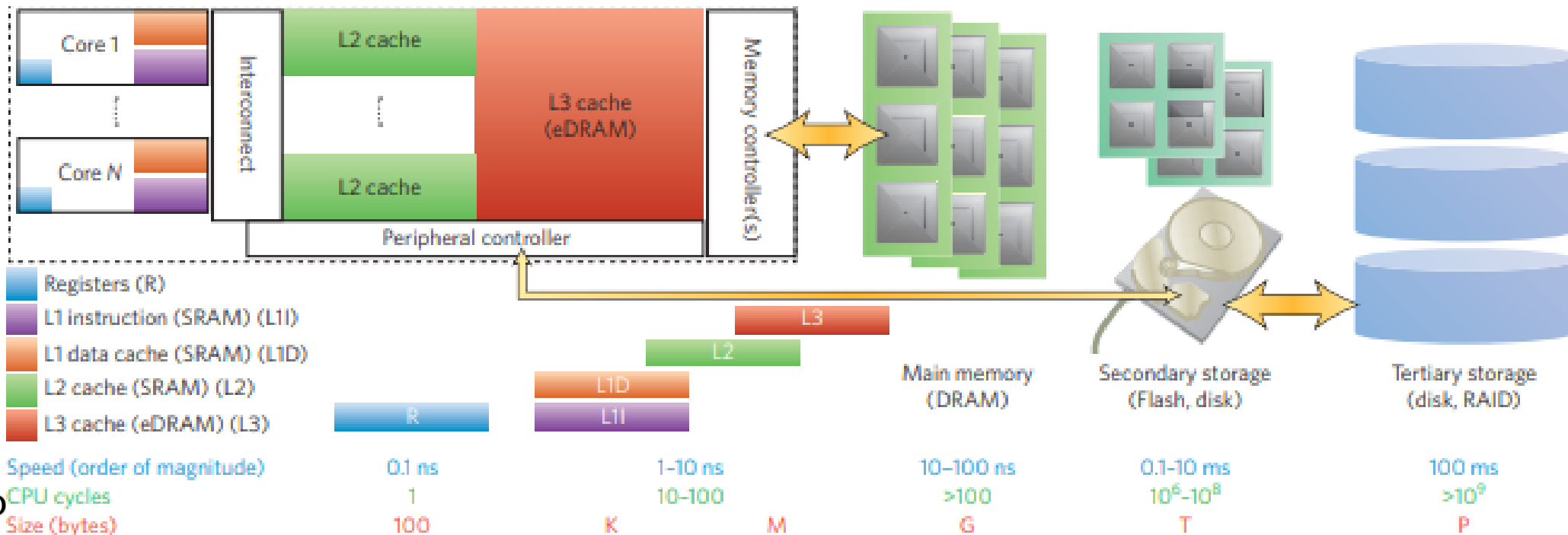
Voltage controlled current source

# MEMORY ORGANIZATION

DRAM

Registers  
and SRAM

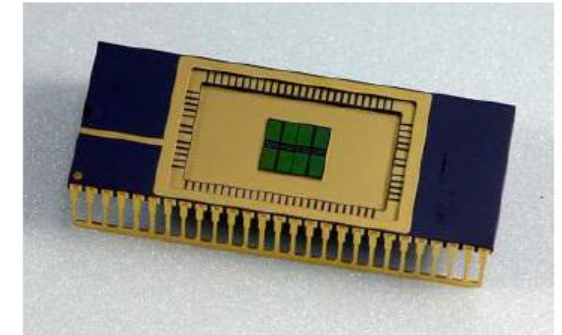
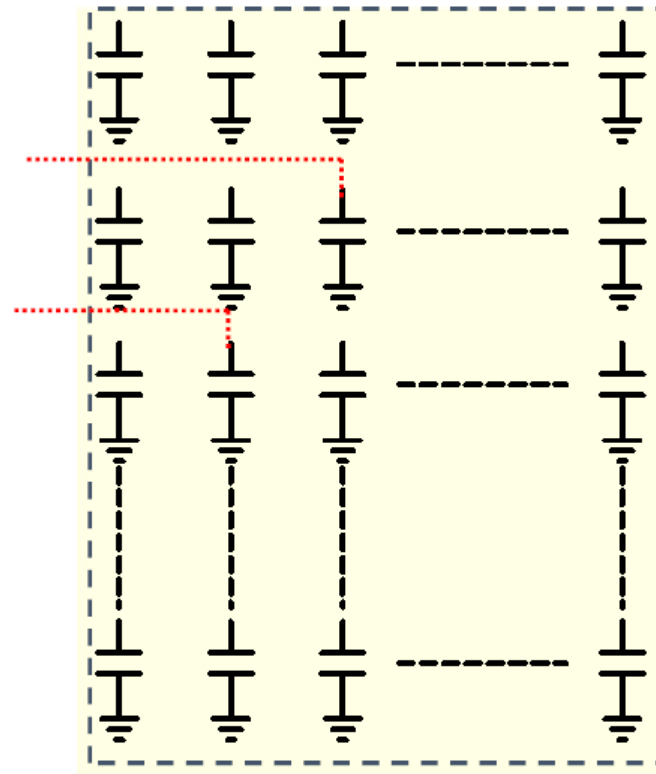
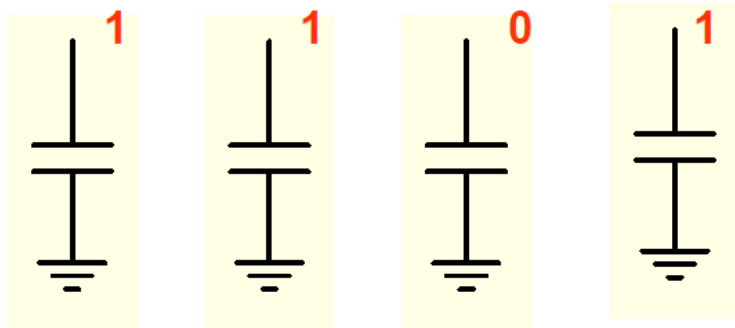
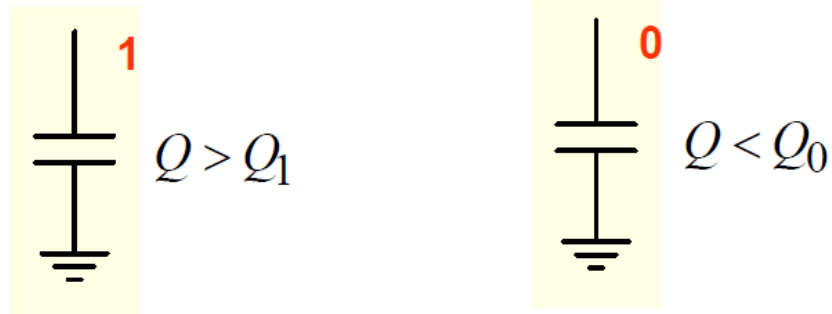
Hard disk



source: H.S.P. Wong  
*et. al.*, Nature  
Nanotechnology,  
Vol. 10, March 2015



# Dynamic RAM



We do not have enough pins to individually access each capacitor !

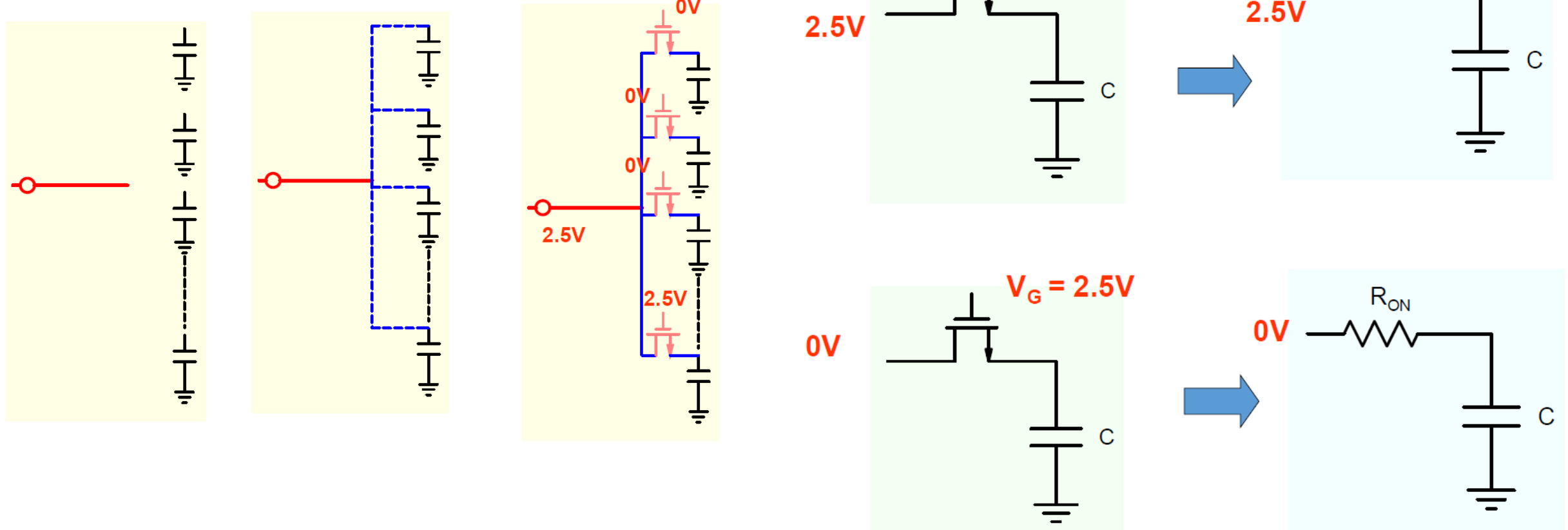
One pin has to be connected to several capacitors !

1101 in binary number format represents number 13

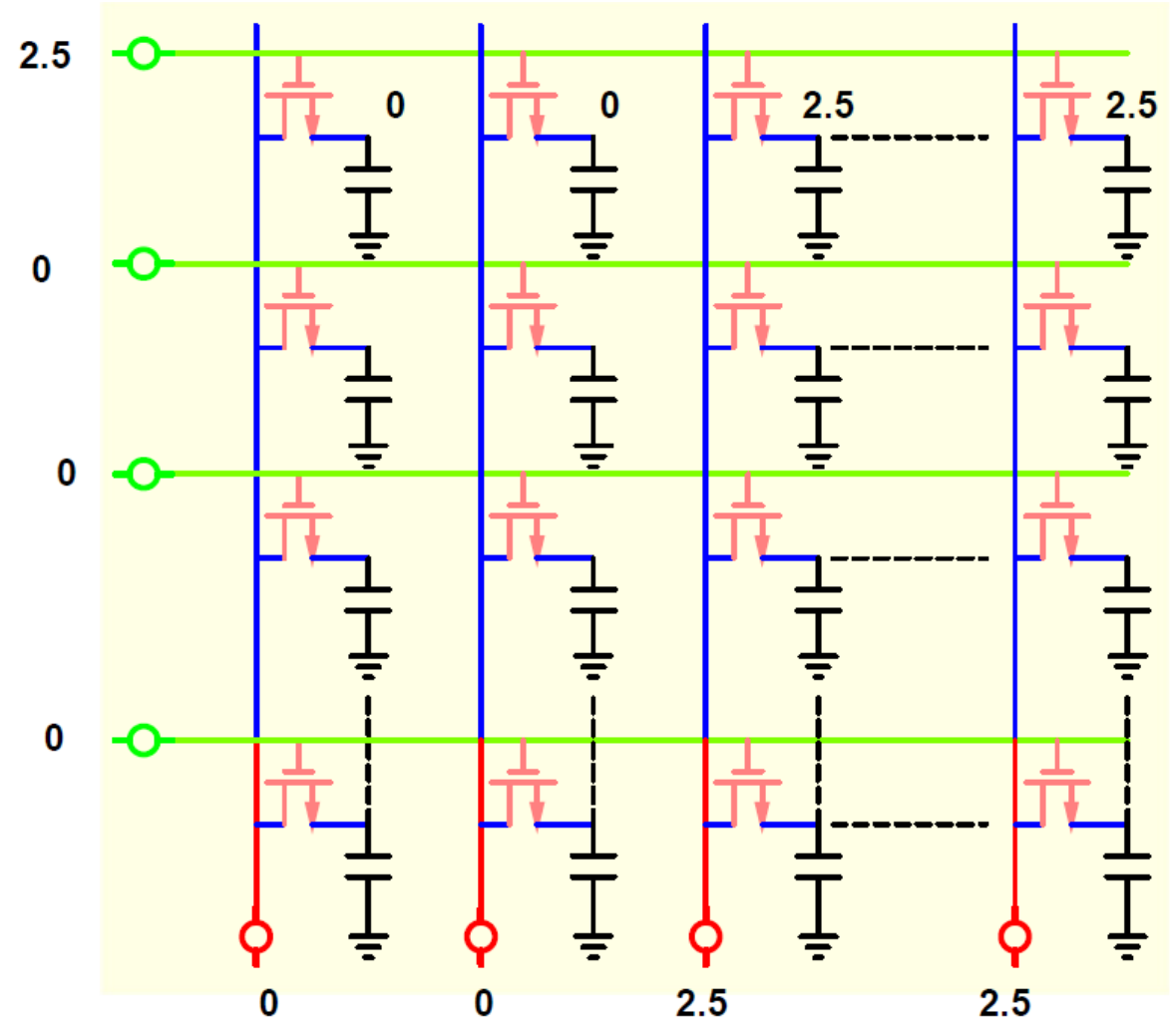
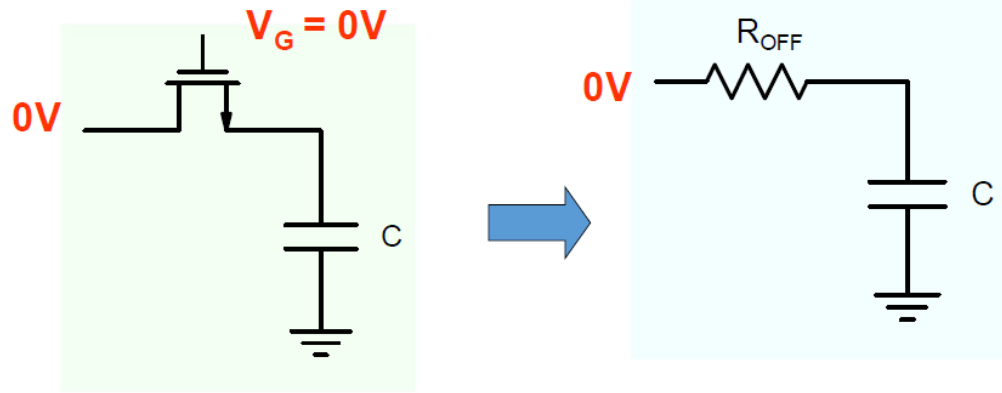
Each capacitor can store 1 bit of information



# Reducing pins in DRAMs



# Crossbar Organization



# Capacitor

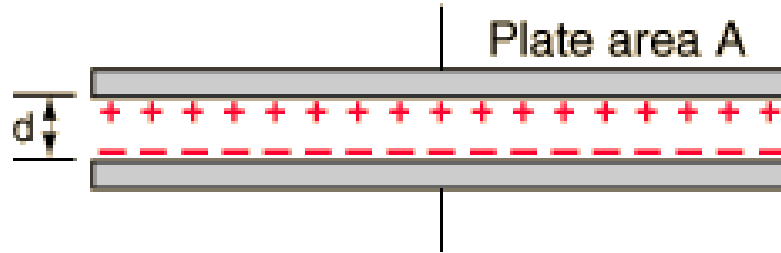
- Two sheets of conductors separated by a layer of insulating material
  - Insulating material is called dielectric - could be air, polyester, ...



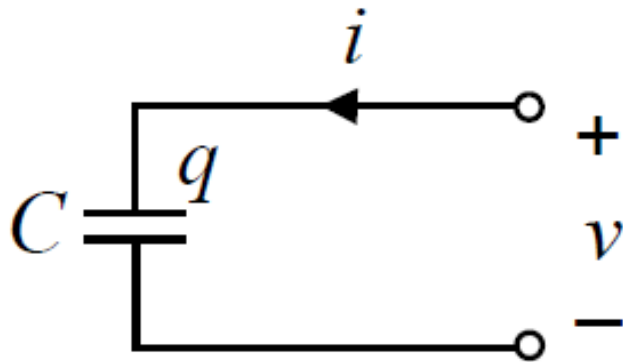
# Capacitors



# Ideal Capacitor



$$C = \frac{\epsilon A}{d} = \frac{k\epsilon_0 A}{d}$$

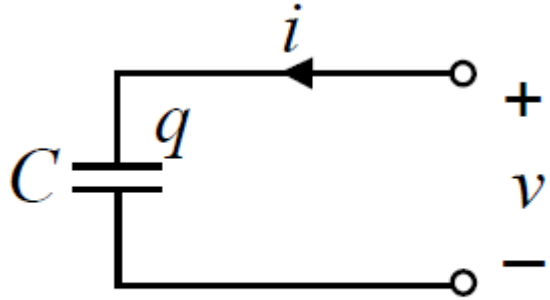


$$q = C v$$

coulombs      farads      volts

Lumped circuit assumption

# Ideal Capacitor



$$q = C v$$

$$i = \frac{dq}{dt}$$

$$= \frac{d(Cv)}{dt}$$

$$= C \frac{dv}{dt}$$

$$i = C \frac{dv}{dt}$$

$$E = \frac{1}{2} C v(t)^2$$

# Capacitor in steady state

$$i = C \frac{dv}{dt}$$

$$v(t) = \frac{1}{C} \int_{t_o}^t i dt + v(t_o)$$

For dc or steady state when the voltage does not vary with time.

$$i = 0$$

A capacitor under DC or steady state acts like an **open circuit**.



# Are capacitors linear?

- Yes! Differentiation and integration are linear operators
- Quick check:

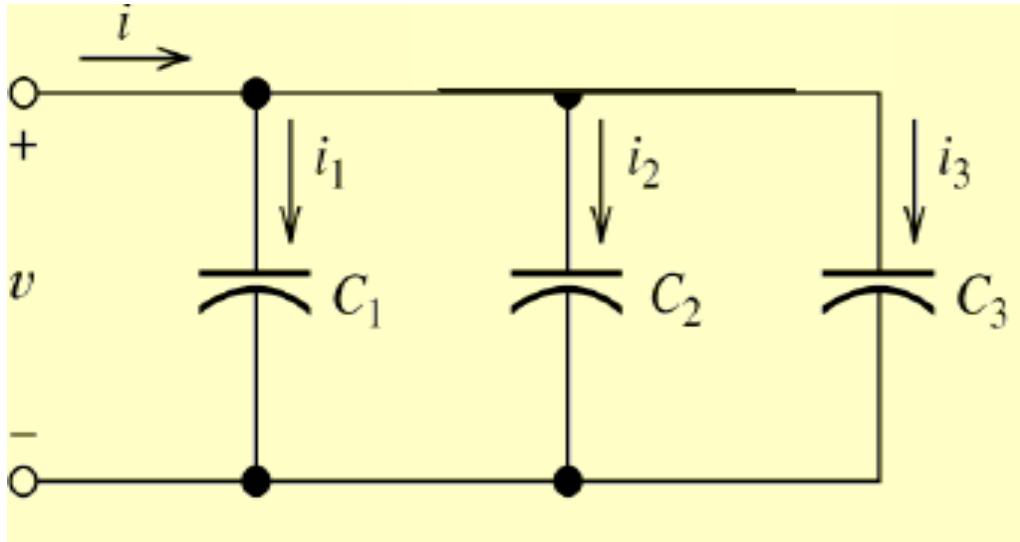
$$i_1(t) = C \frac{dv_1(t)}{dt}$$

$$i_2(t) = C \frac{dv_2(t)}{dt}$$

$$\alpha i_1(t) + \beta i_2(t) = C \frac{d}{dt}(\alpha v_1(t) + \beta v_2(t)) = \alpha C \frac{dv_1(t)}{dt} + \beta C \frac{dv_2(t)}{dt}$$

- Consequence: can use superposition, combination rules, Thevenin/Norton

# Capacitor: series/parallel

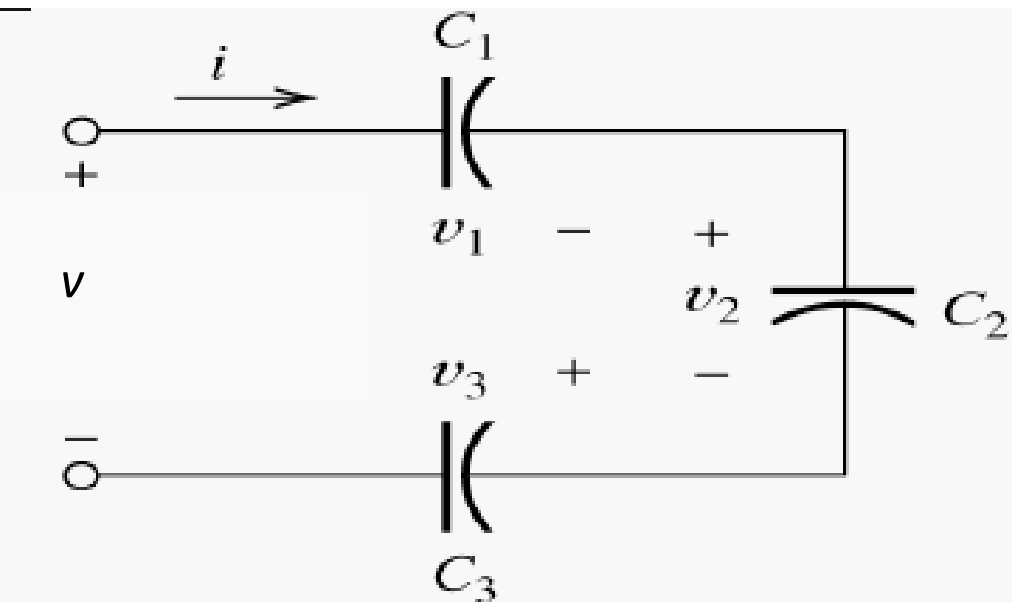


$$i_1 = C_1 \frac{dv}{dt} \quad i_2 = C_2 \frac{dv}{dt} \quad i_3 = C_3 \frac{dv}{dt}$$
$$i = i_1 + i_2 + i_3 = C_1 \frac{dv}{dt} + C_2 \frac{dv}{dt} + C_3 \frac{dv}{dt}$$

$$i = (C_1 + C_2 + C_3) \frac{dv}{dt}$$

$$i = C_{eq} \frac{dv}{dt}$$

$$C_{eq} = C_1 + C_2 + C_3$$

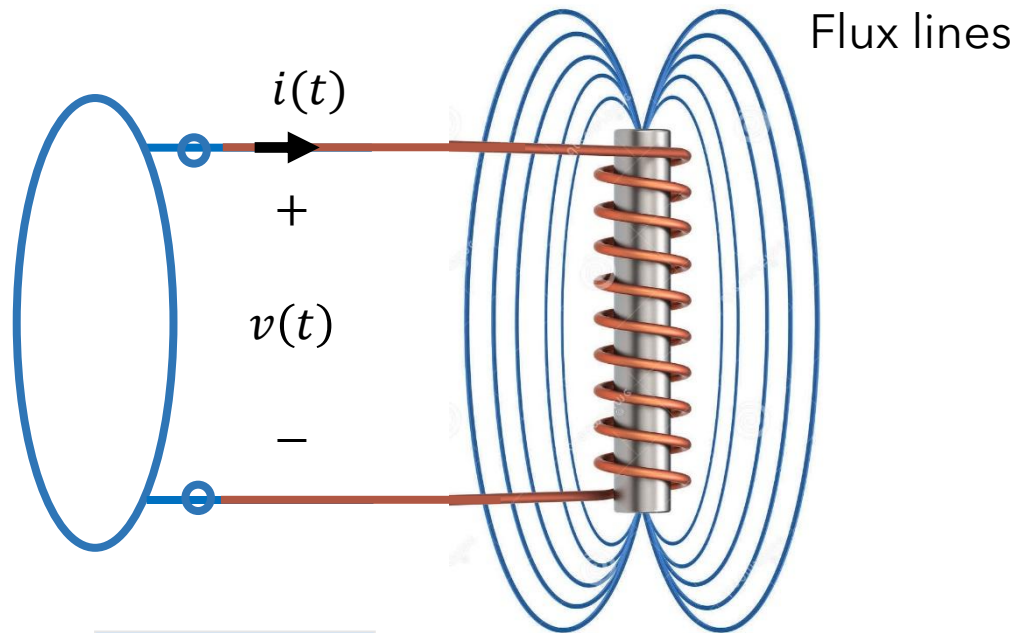


$$\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3}$$

# Inductors

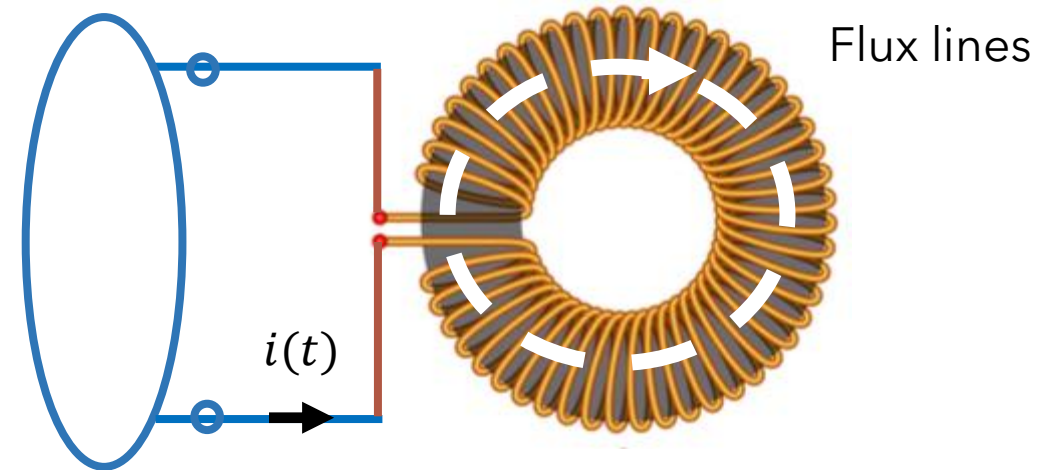


# Inductors



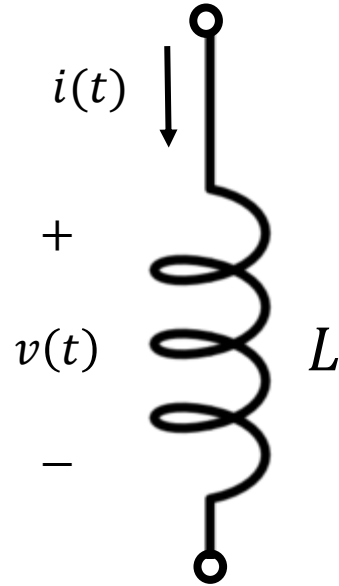
$$\varphi = L \times i$$

$$v = \frac{d\varphi}{dt} = L \times \frac{di}{dt}$$



$$E = \frac{1}{2} L i(t)^2$$

# Inductance



$$v = L \frac{di}{dt}$$

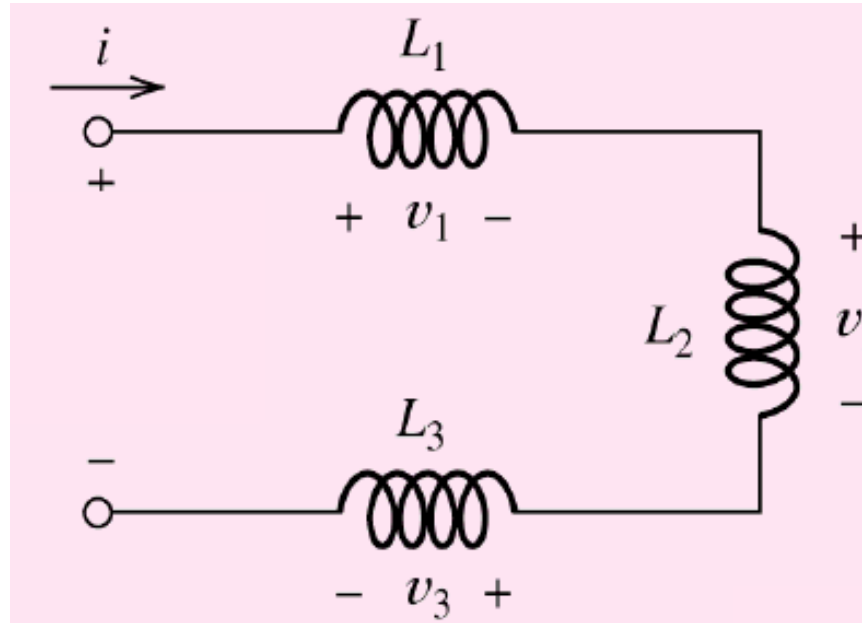
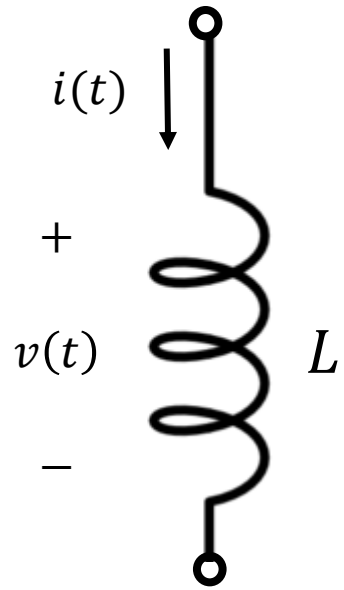
↓  
**Henry**

For dc or steady state when the current does not vary with time.

$$v = 0$$

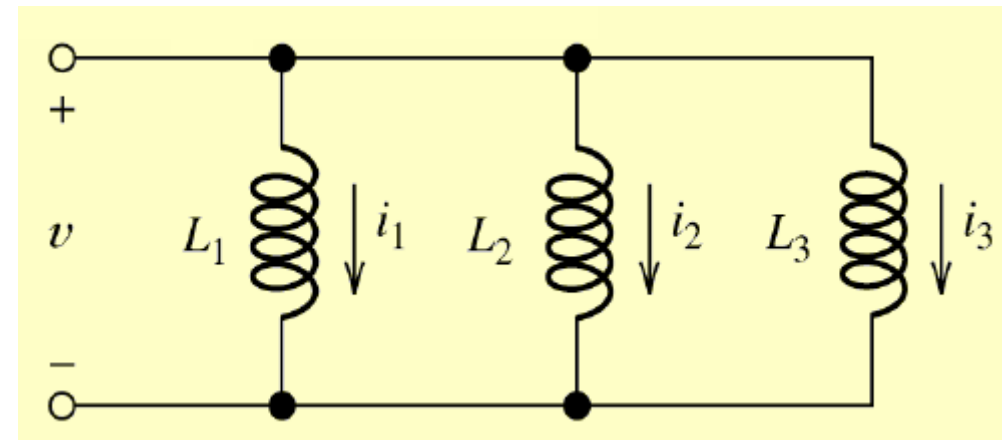
An inductor under DC or steady state acts like a **short circuit**

# Inductors: series/parallel



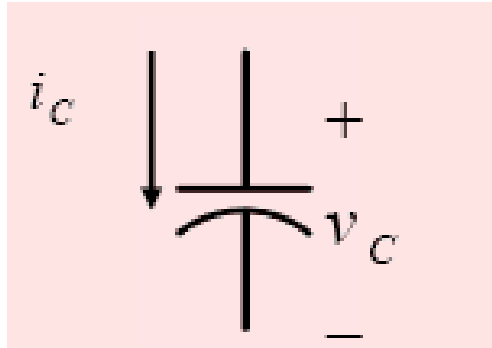
$$L_{eq} = L_1 + L_2 + L_3$$

$$\frac{1}{L_{eq}} = \frac{1}{L_1} + \frac{1}{L_2} + \frac{1}{L_3}$$



# Two things to remember

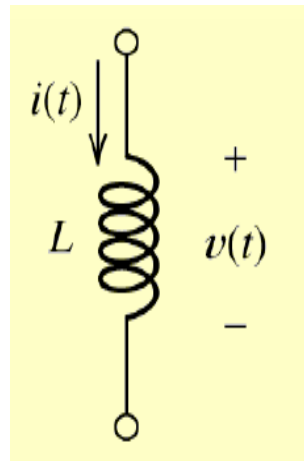
## Voltage across a capacitor cannot change instantaneously



$$i_c = C \frac{dv_c}{dt}$$

Instantaneous change in voltage implies infinite current!

## Current through an inductor cannot change instantaneously

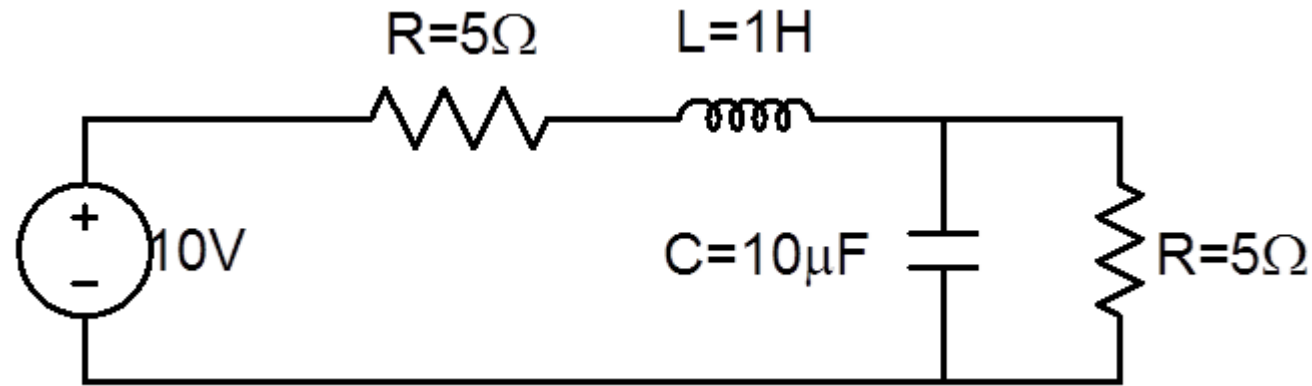


$$v = L \frac{di}{dt}$$

Instantaneous change in current implies infinite voltage!



# Circuit analysis: Example 1

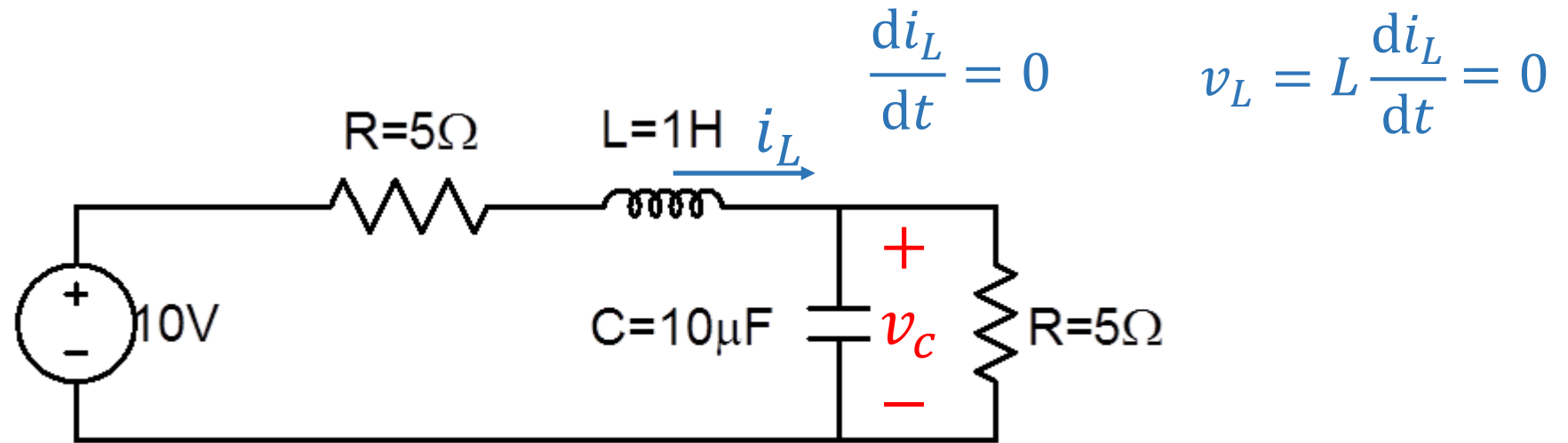


What is current through the inductor or voltage across the capacitor ?

We cannot have an answer unless we have some knowledge of the past state of the circuit.

Suppose we are told that circuit has been in this state for a very long time.

# Circuit analysis: Example 1



$$\frac{di_L}{dt} = 0$$

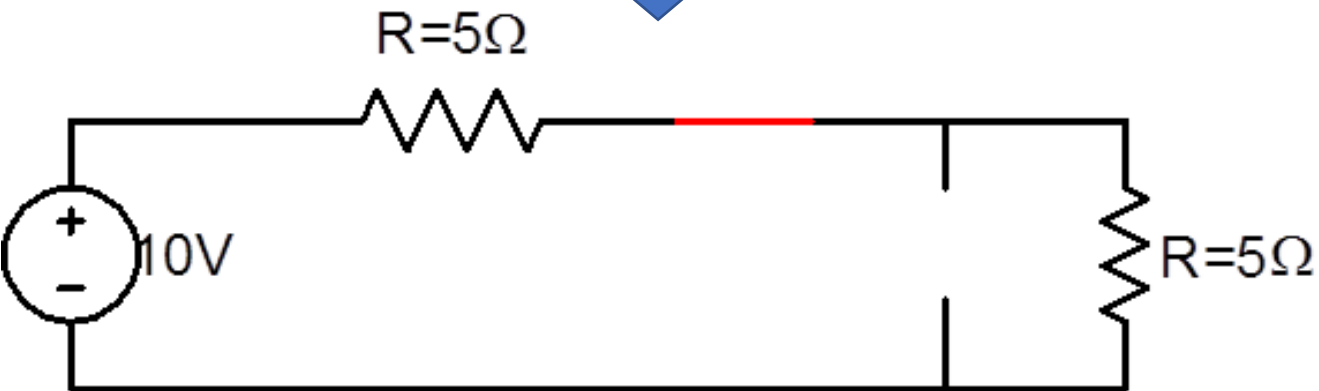
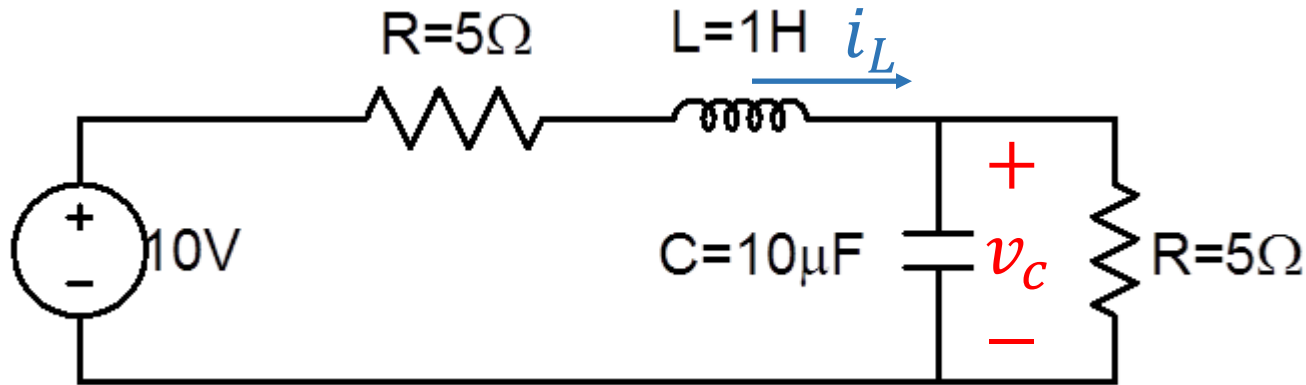
$$v_L = L \frac{di_L}{dt} = 0$$

$$\frac{dv_c}{dt} = 0$$

$$i_c = C \frac{dv_c}{dt} = 0$$

Suppose we are told that circuit has been in this state for a very long time.

# Example 1: Steady state behavior



$$\frac{di_L}{dt} = 0$$

$$\frac{dv_c}{dt} = 0$$

$$v_L = L \frac{di_L}{dt} = 0$$

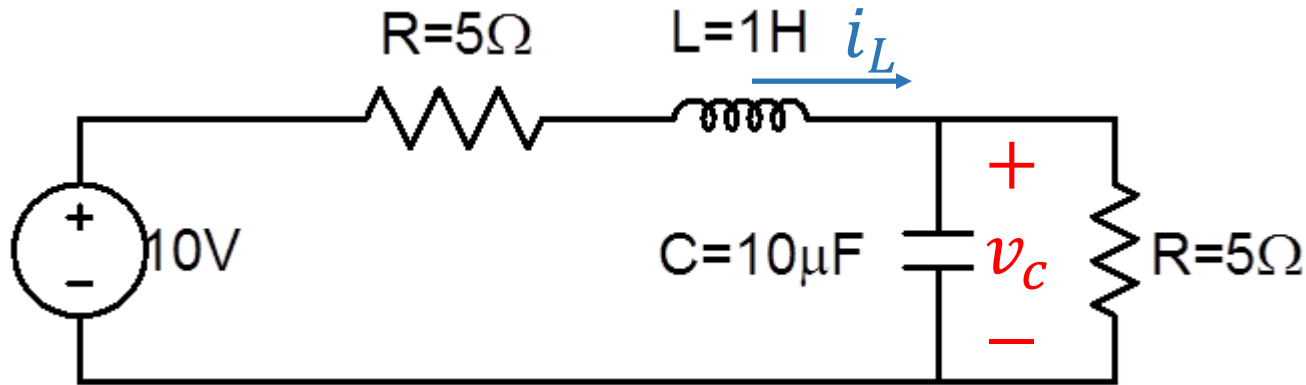
$$i_c = C \frac{dv_c}{dt} = 0$$

A capacitor under dc or steady state acts like an **open circuit**.

An inductor under dc or steady state acts like a **short circuit**.

Suppose we are told that circuit has been in this state for a very long time.

# Example 1: Steady state behavior

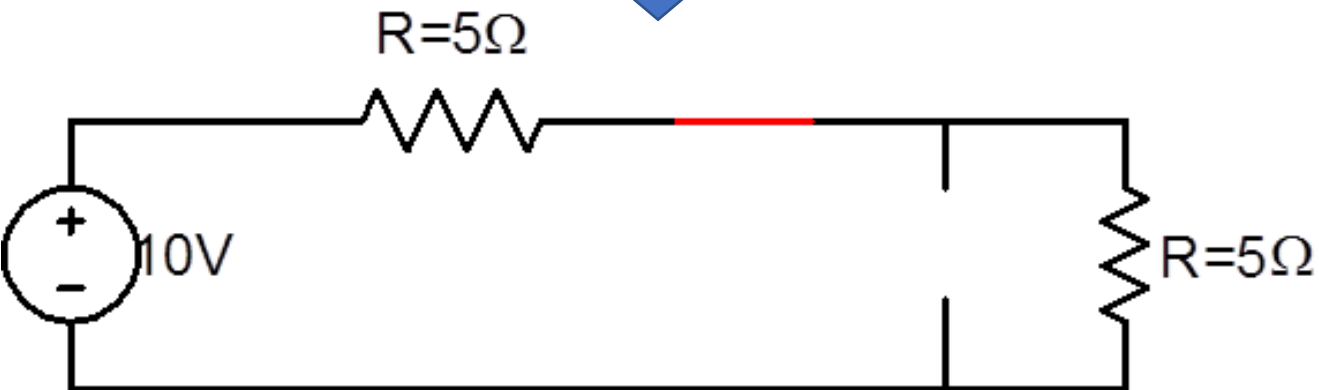


$$\frac{di_L}{dt} = 0$$

$$v_L = L \frac{di_L}{dt} = 0$$

$$\frac{dv_C}{dt} = 0$$

$$i_C = C \frac{dv_C}{dt} = 0$$

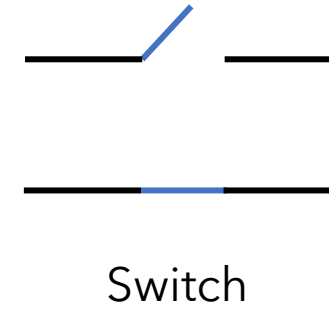
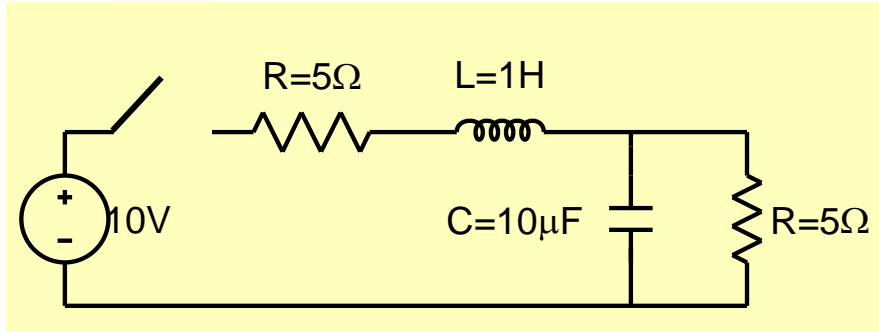


A capacitor under dc or steady state acts like an **open circuit**.

An inductor under dc or steady state acts like a **short circuit**.

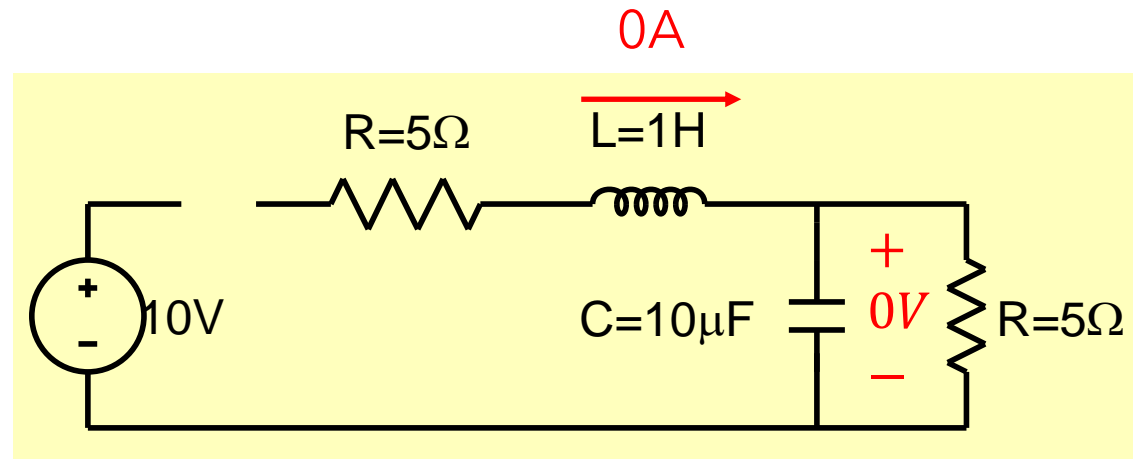
Suppose we are told that circuit has been in this state for a very long time.

# Example 2: Immediate behavior after a change



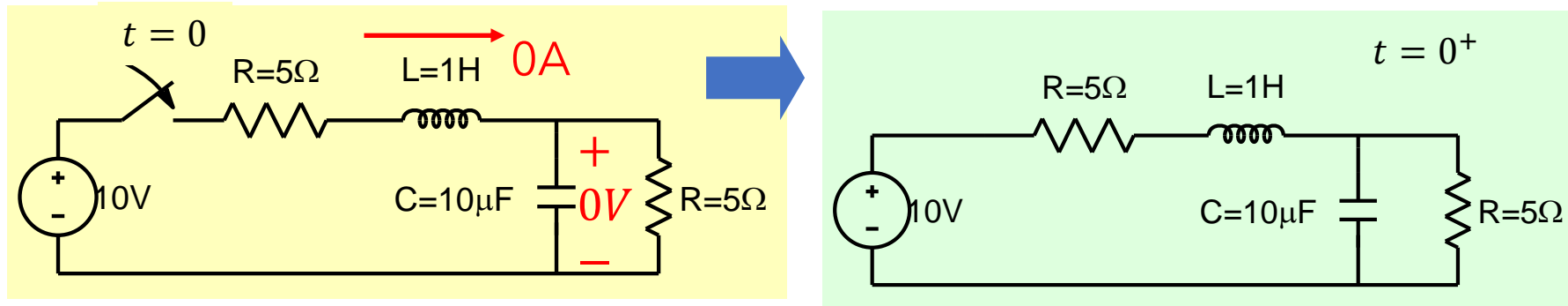
Switch open -  
Disconnected  
Switch closed -  
connected

Circuit before switching



# Example 2: Immediate behavior after a change

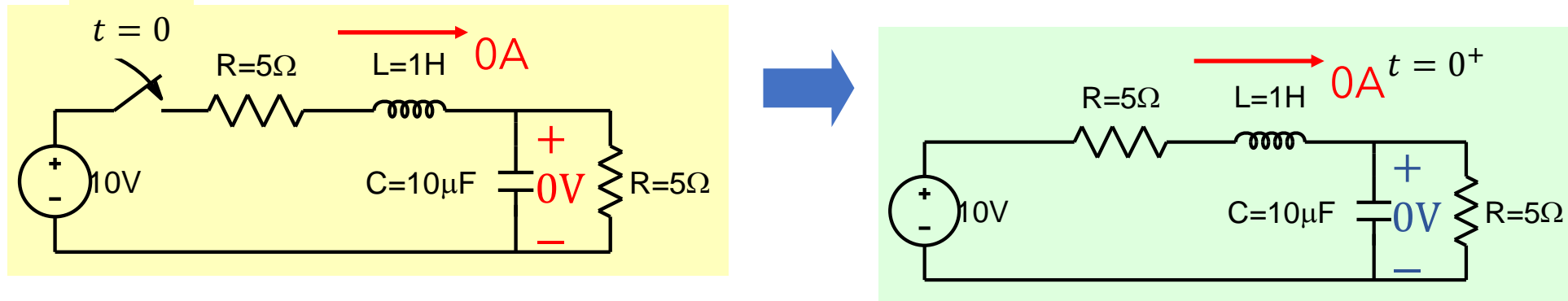
Suppose the circuit was switched on at  $t = 0$  second.



Find voltage and current immediately after closing the switch.

# Example 2: Immediate behavior after a change

Suppose the circuit was switched on at  $t = 0$  second.



Find voltage and current immediately after closing the switch.

Current through an inductor  
cannot change instantaneously

Voltage across a capacitor cannot change  
instantaneously



# Example 2: Steady state behavior after a change

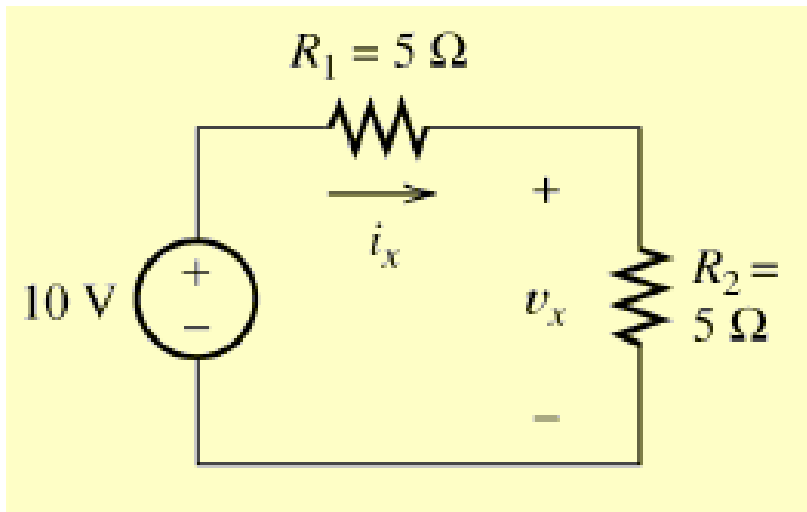
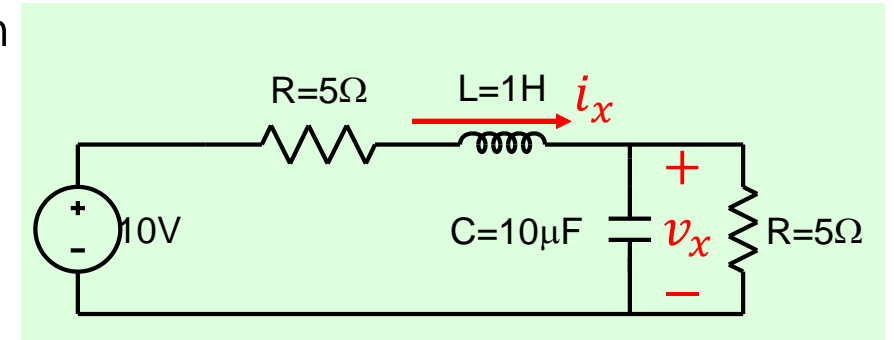
Find voltage and current a long time after closing the switch

$$t \rightarrow \infty$$

Recall

A capacitor under dc or steady state acts like an **open circuit**.

An inductor under dc or steady state acts like a **short circuit**



$$i_x = \frac{10}{R_1 + R_2} = 1 \text{ A}$$

$$v_x = R_2 i_x = 5 \text{ V}$$

$$i_L(t \rightarrow \infty) = 1 \text{ A}$$

$$v_c(t \rightarrow \infty) = 5 \text{ V}$$